

Spring 2019 Purdue University

ECE 255: L7

Ideal and Real Diodes

(Sedra and Smith, 4.1-4.2)

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Announcements

No office hours today.

(Remember, you can always email me to set up another time.)

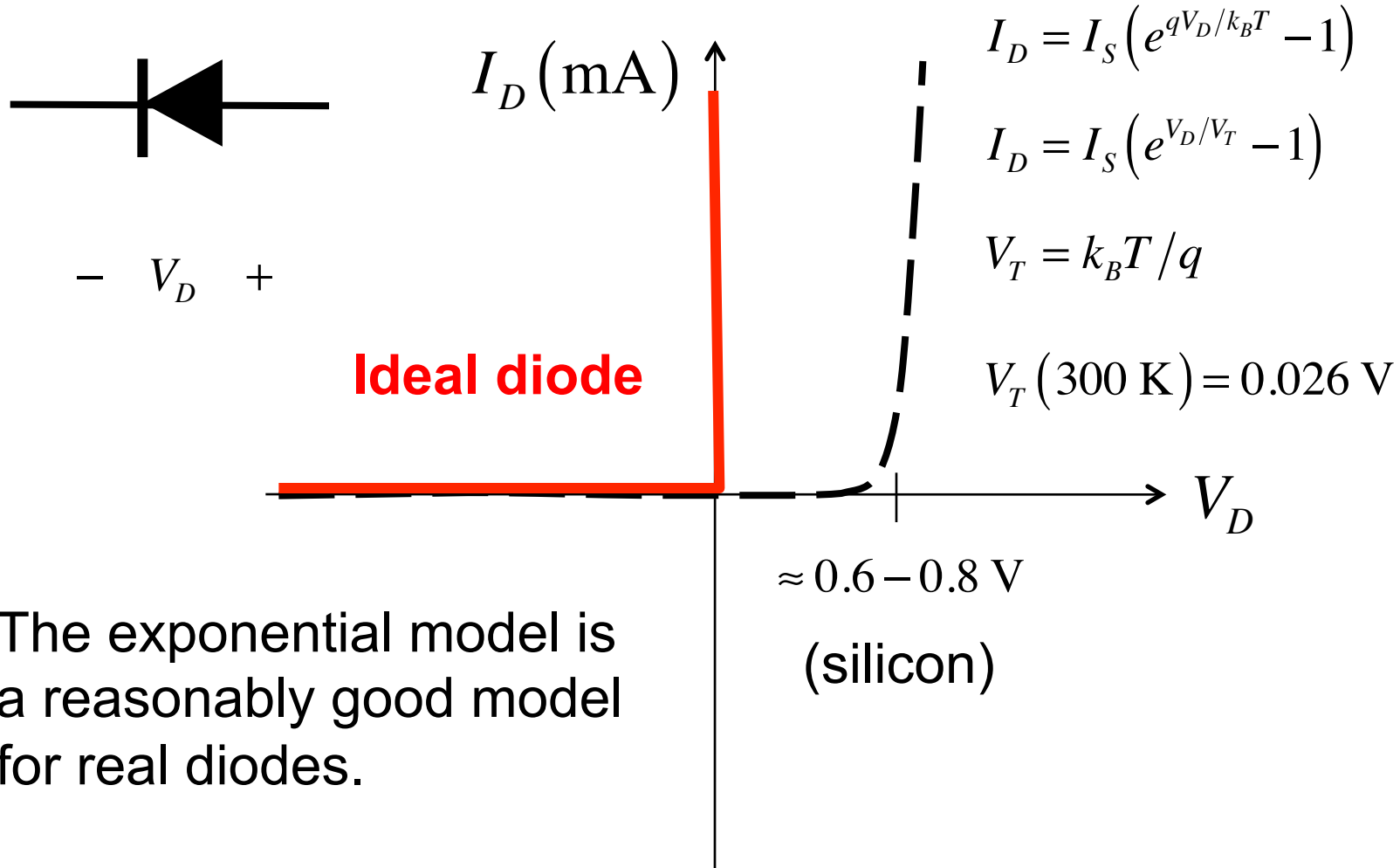
Exam 1: Thursday, Feb. 7, 6:30 PM, LILY 1105.

(Weeks -1- 4 topics, semiconductors, diodes, BJTs)

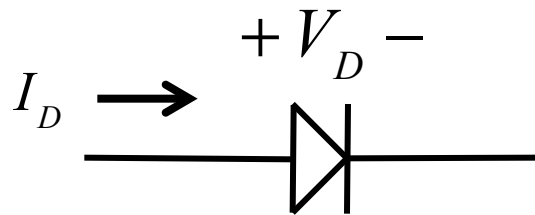
Ideal and Real Diodes

- 1) Ideal vs. real diodes
- 2) Circuit analysis using ideal diodes
- 3) Circuit analysis using “real” diodes

Ideal vs. real diodes



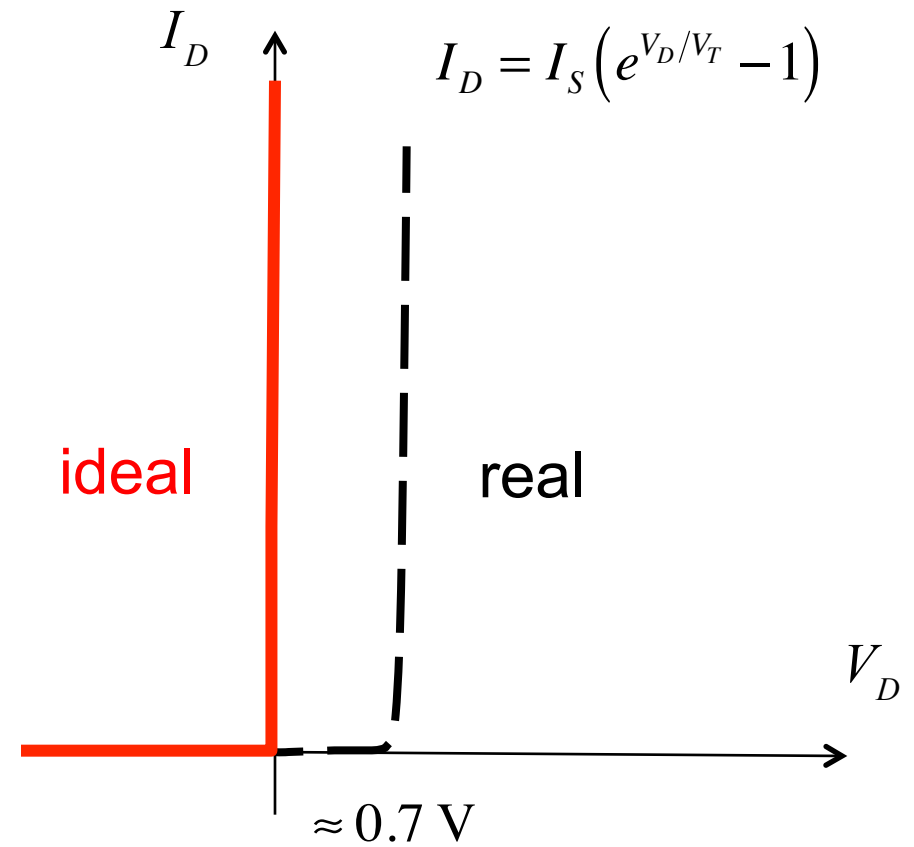
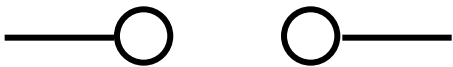
“Ideal” diode model



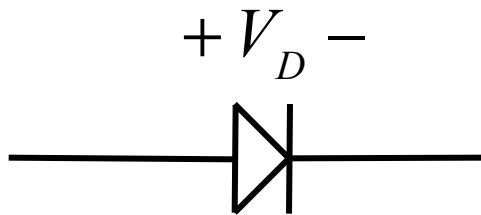
$V_D = 0$



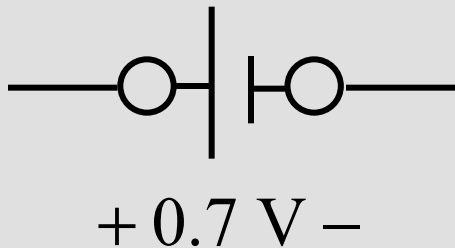
$V_D < 0$



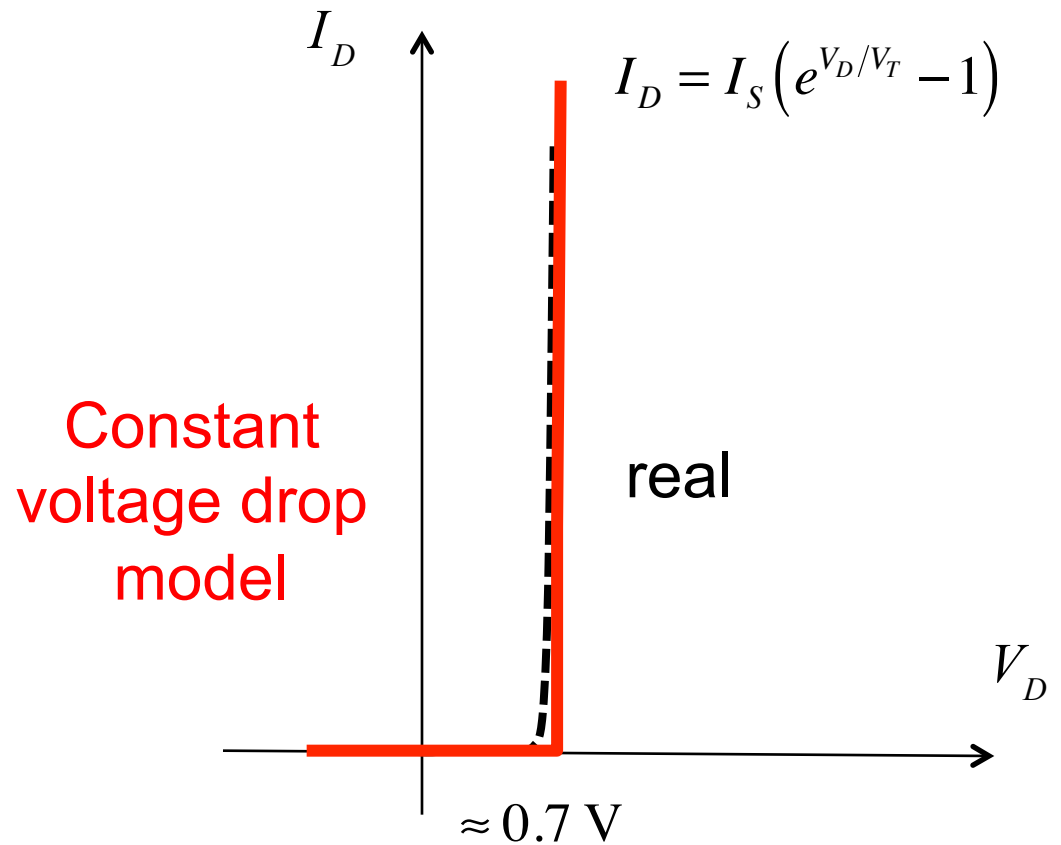
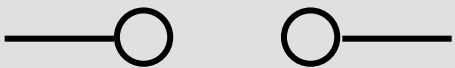
Constant-voltage-drop model



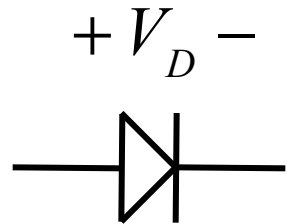
$$V_D \geq 0.7 \text{ V}$$



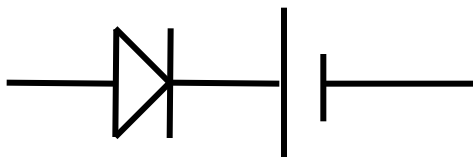
$$V_D < 0.7 \text{ V}$$



Constant-voltage-drop model



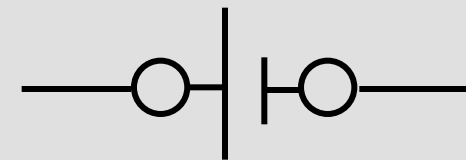
$+0.7\text{ V} -$



Ideal diode

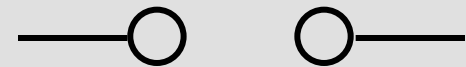
Ideal battery

$V_D \geq 0.7$

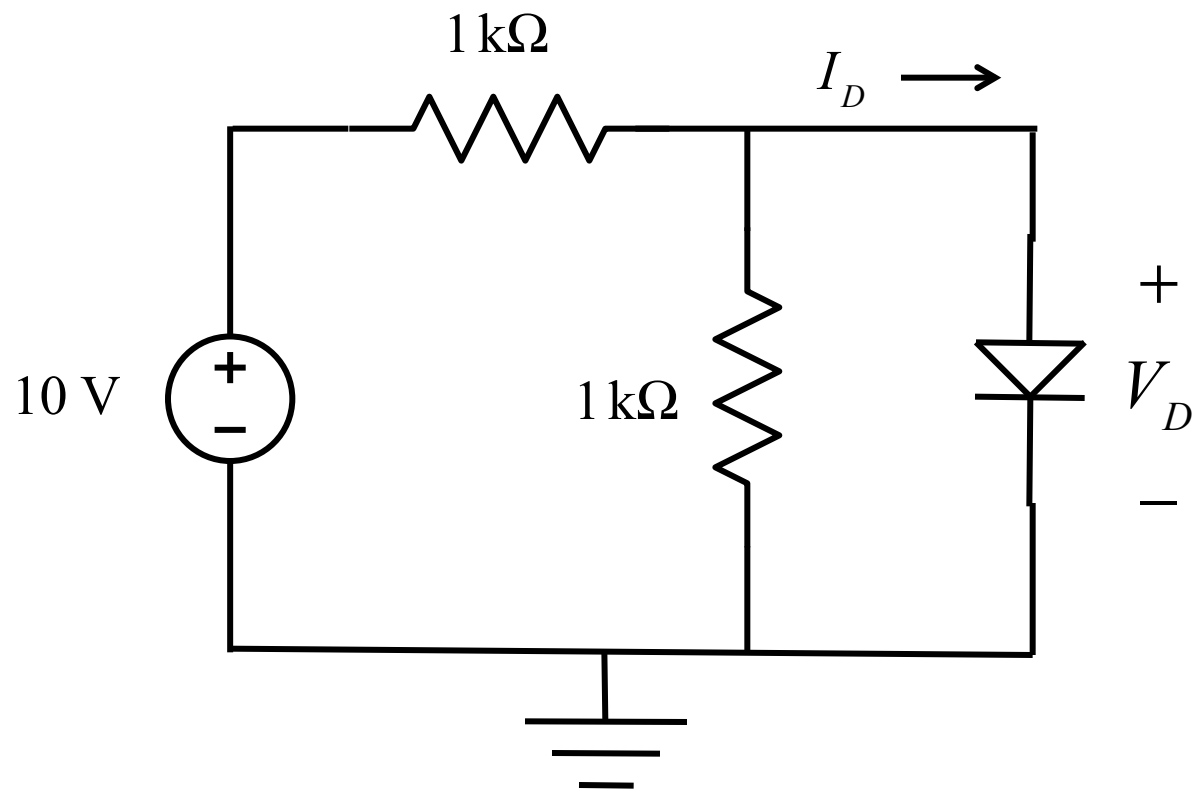


$+0.7 -$

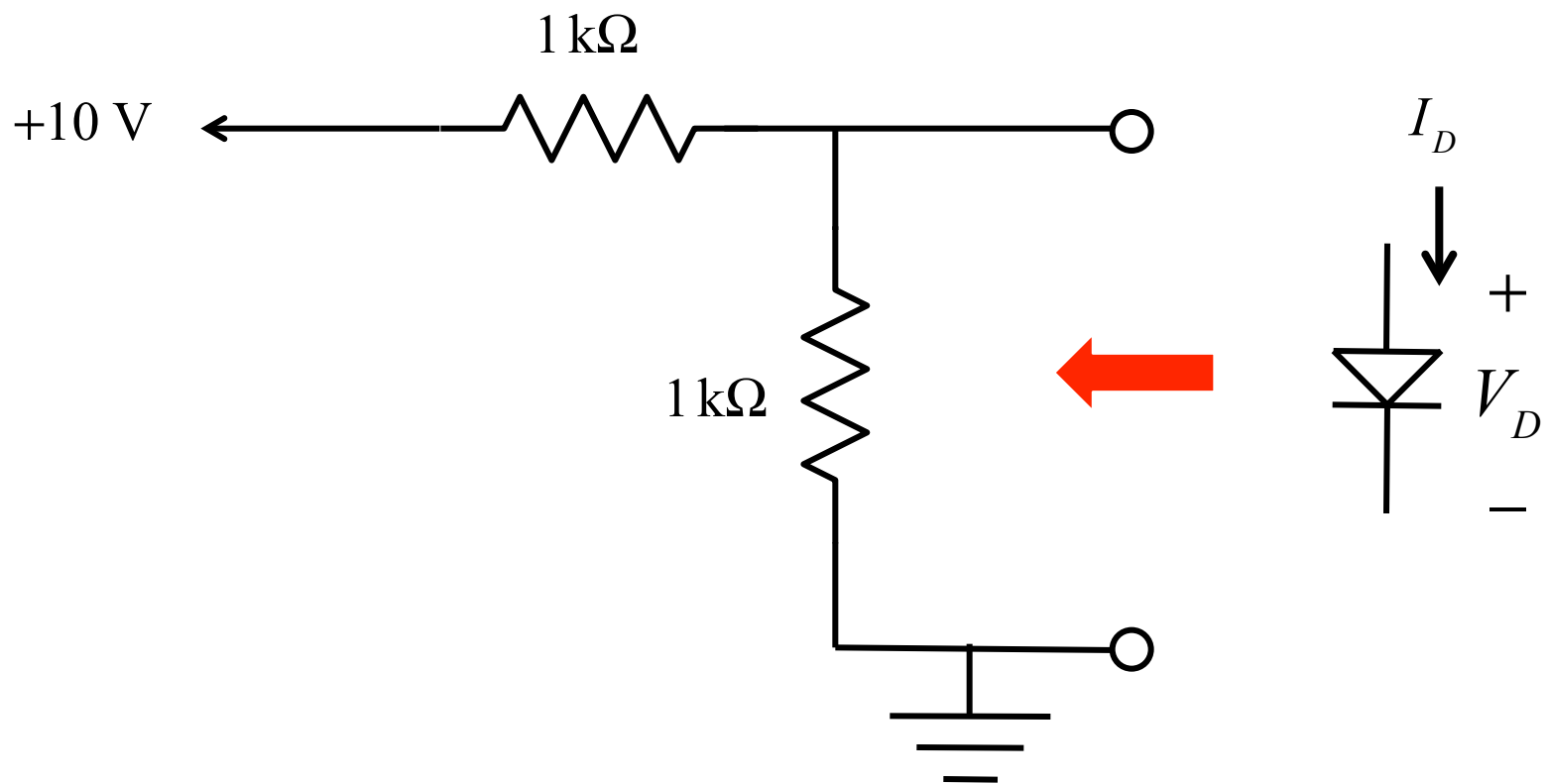
$V_D < 0.7$



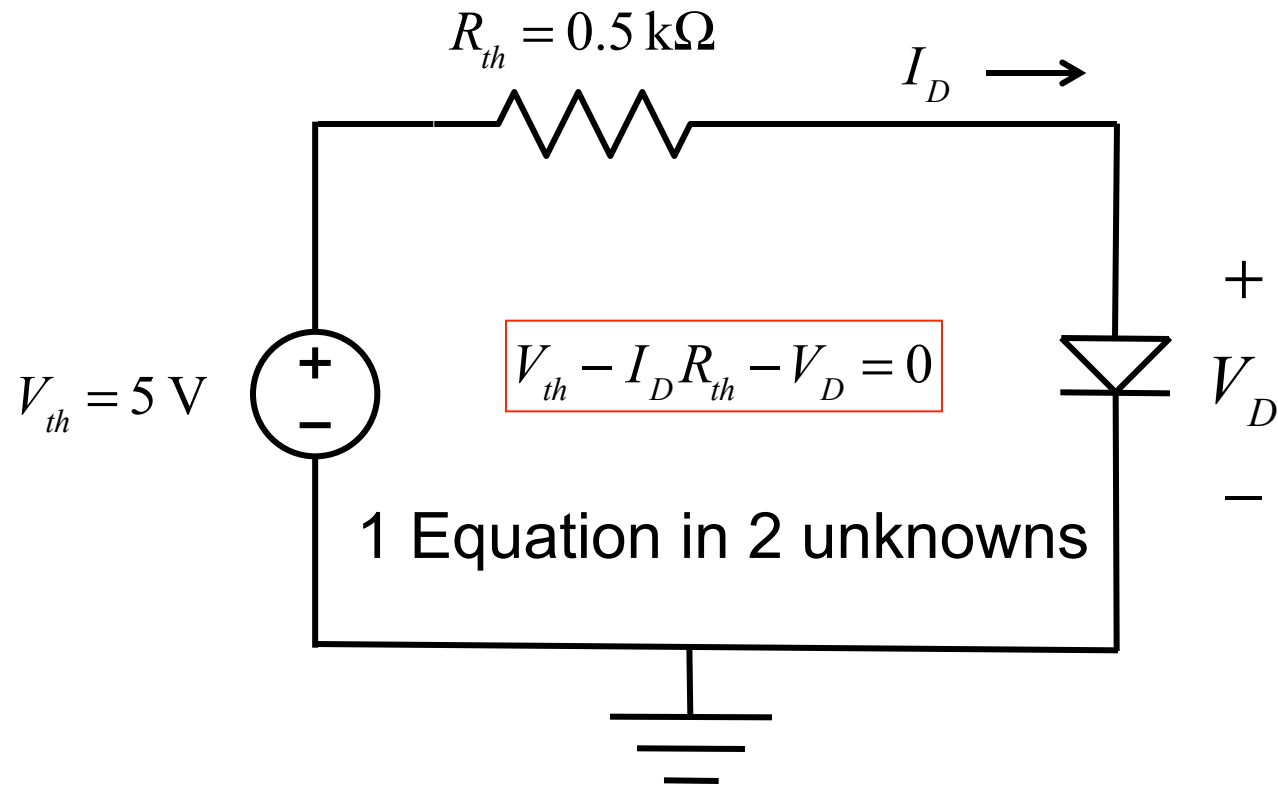
A simple circuit to analyze



Let's make it even simpler

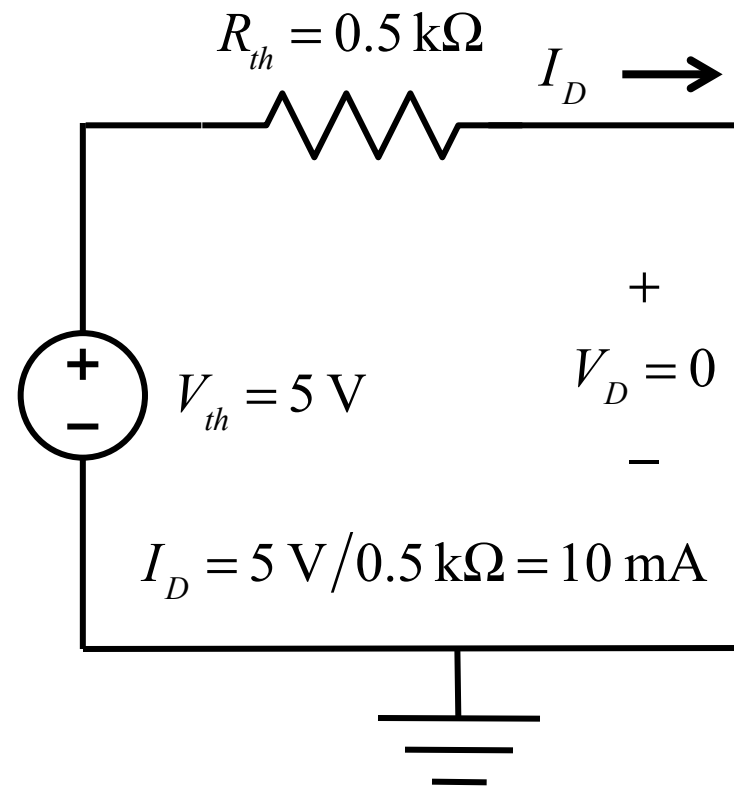
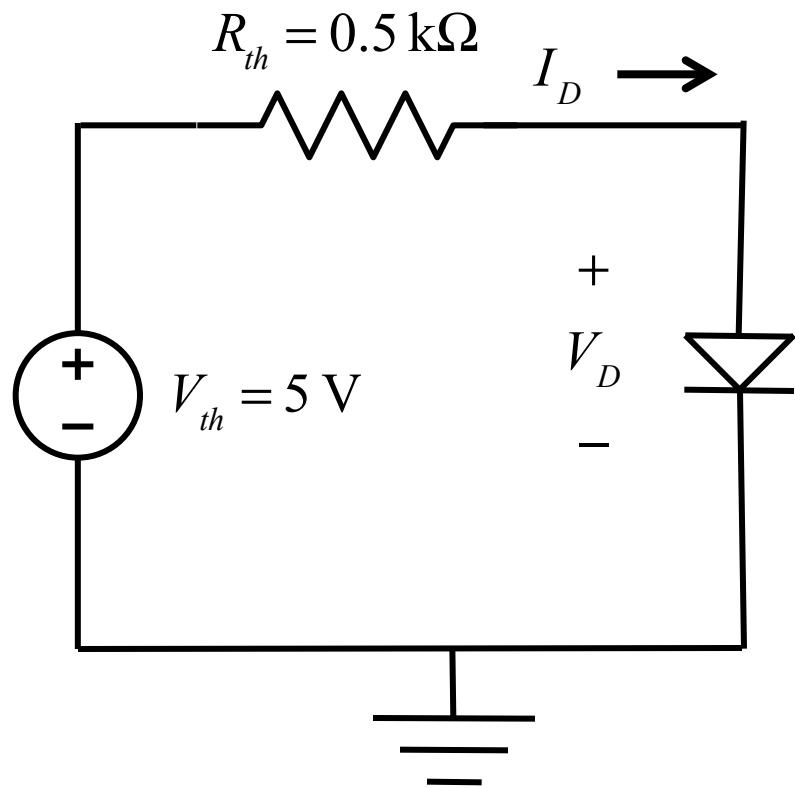


Analyze the circuit



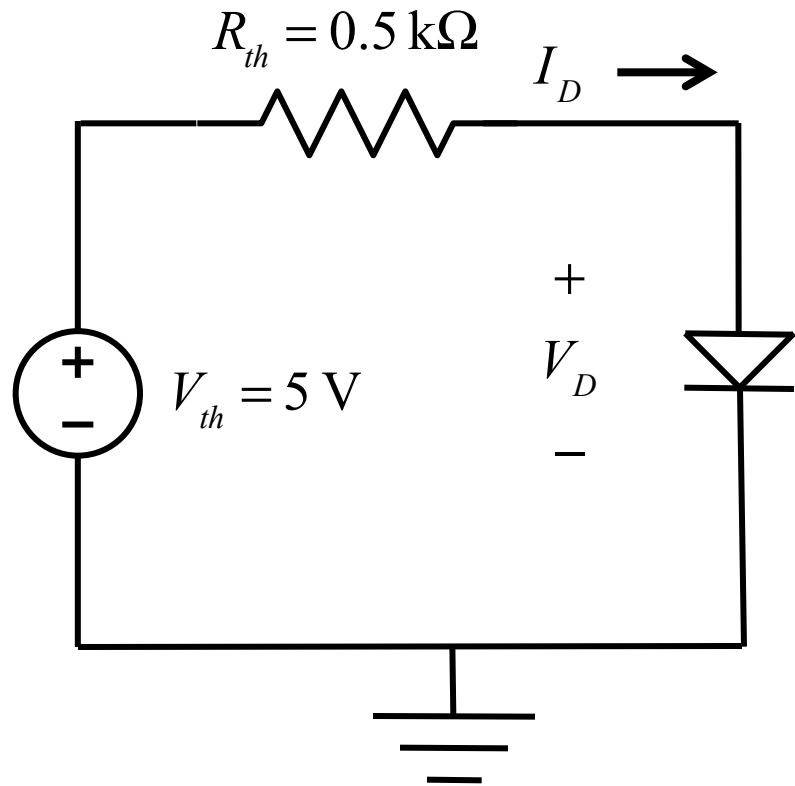
Need an equation for $V_D(I_D)$ or $I_D(V_D)$

1) Ideal diode analysis ($V_D = 0$)

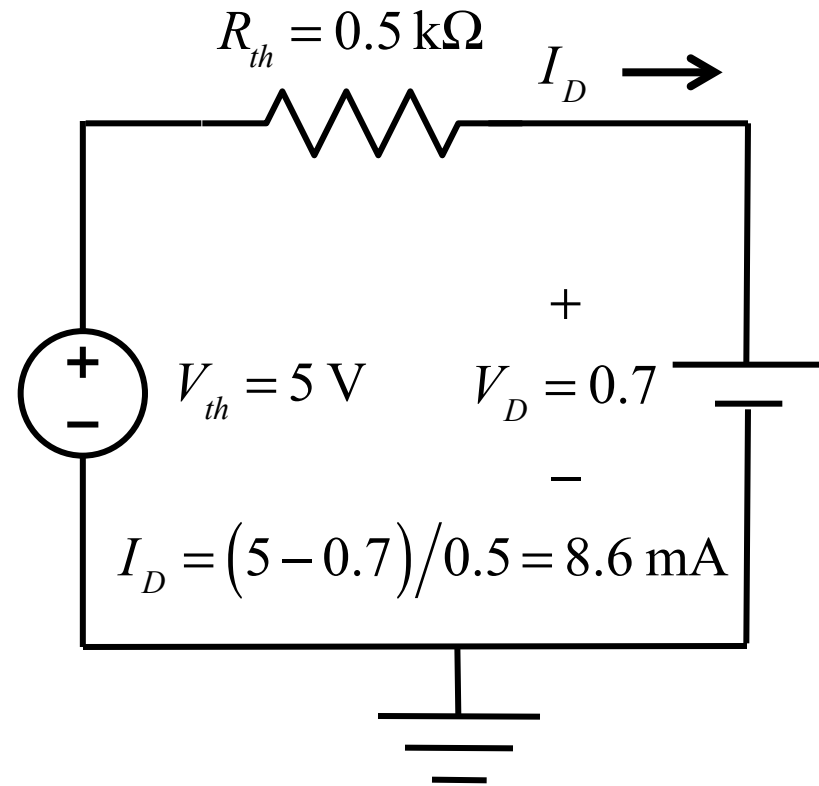


(Exact: $I_D = 8.61\text{ mA}$)

2) Constant-voltage-drop model ($V_D = 0.7 \text{ V}$)



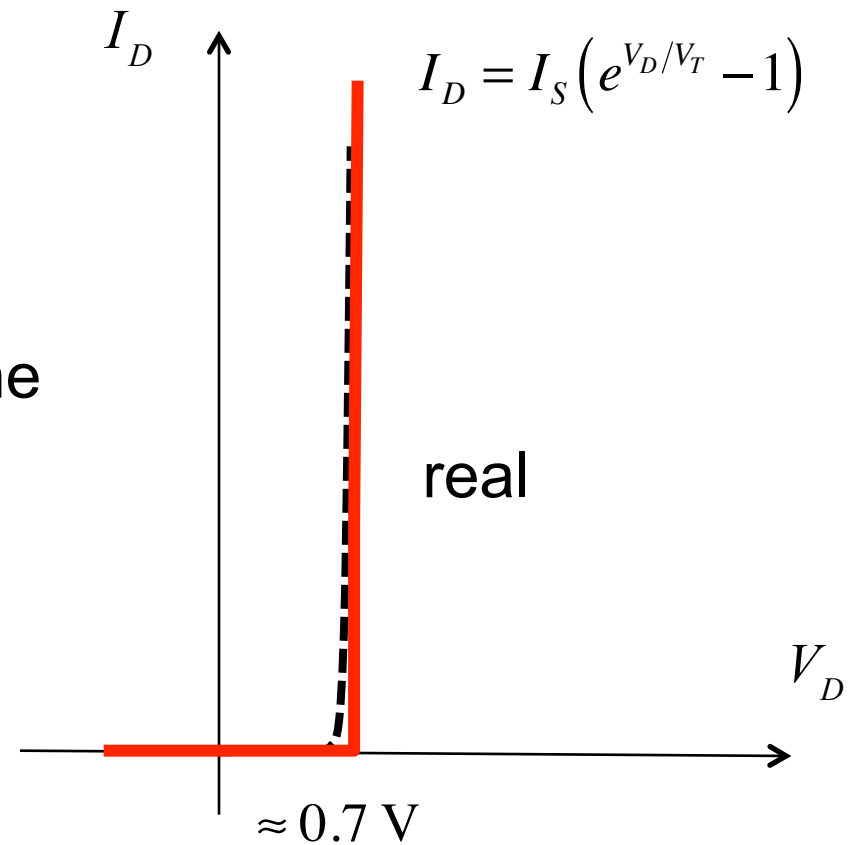
$$I_D = (5 - 0.7) \text{ V} / 0.5 \text{ k}\Omega = 8.6 \text{ mA}$$



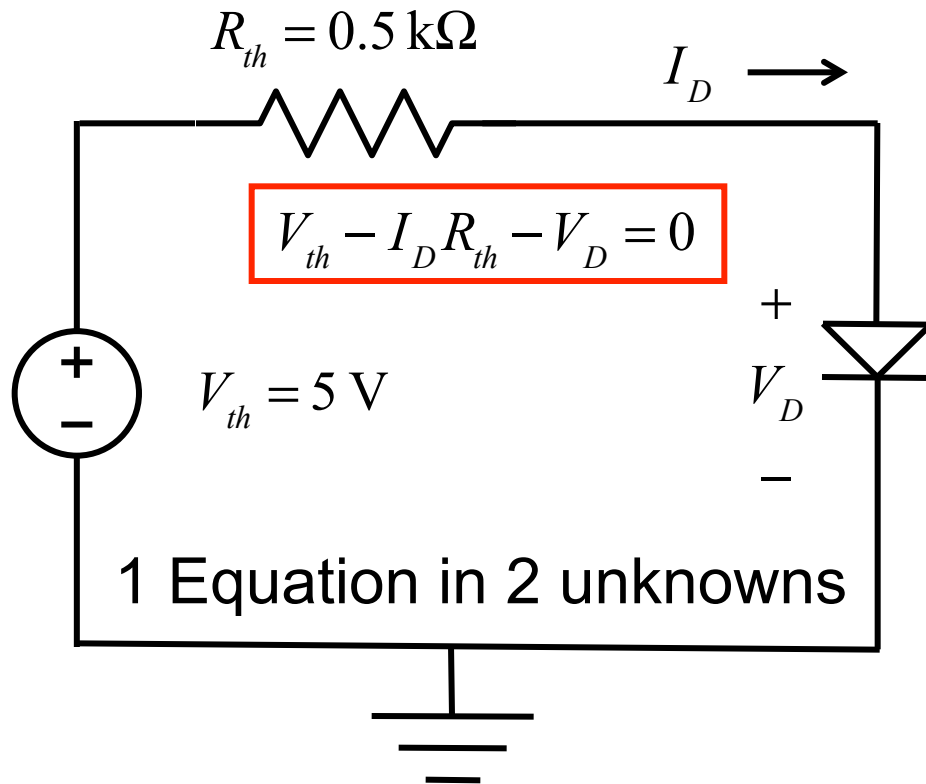
$$(\text{Exact: } I_D = 8.61 \text{ mA})$$

Constant-voltage-drop model

In this case, our model was a very good approximation to the actual diode.



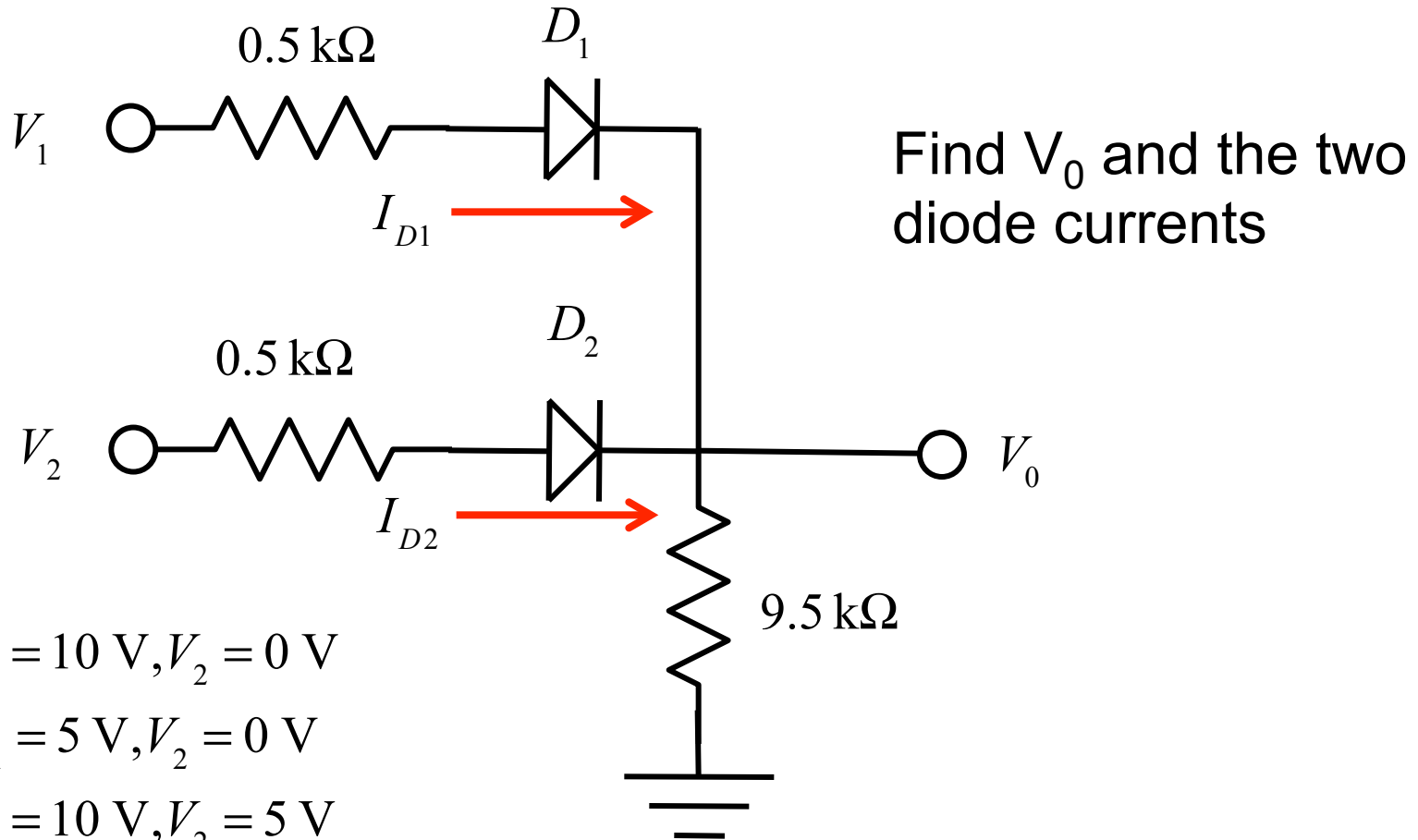
Analyzing diode circuits



- 1) Ideal diode model ($V_D = 0$)
- 2) Constant-diode-drop model ($V_D \sim 0.7$)
- 3) Diode equation?

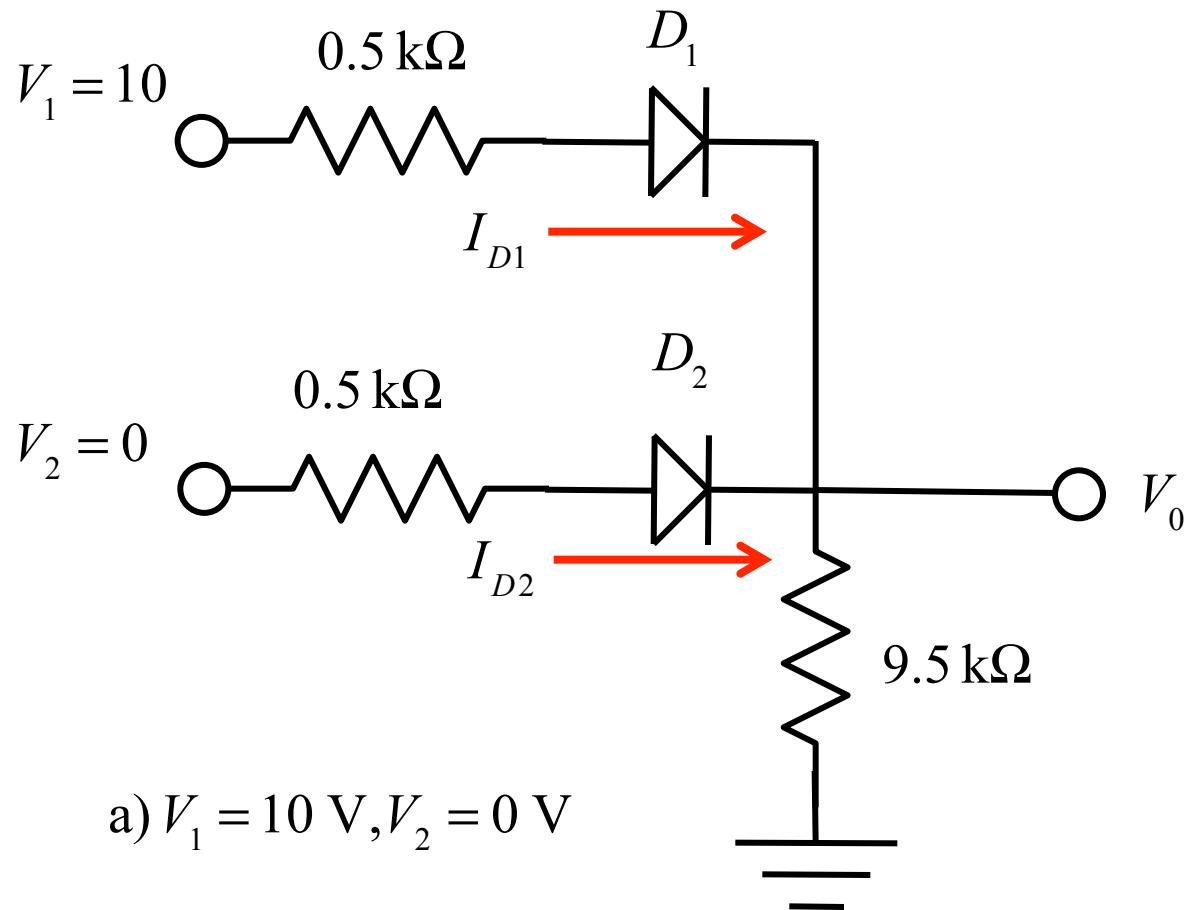
Need another equation for $V_D(I_D)$ or $I_D(V_D)$

Examples (assume the constant-V-drop model)



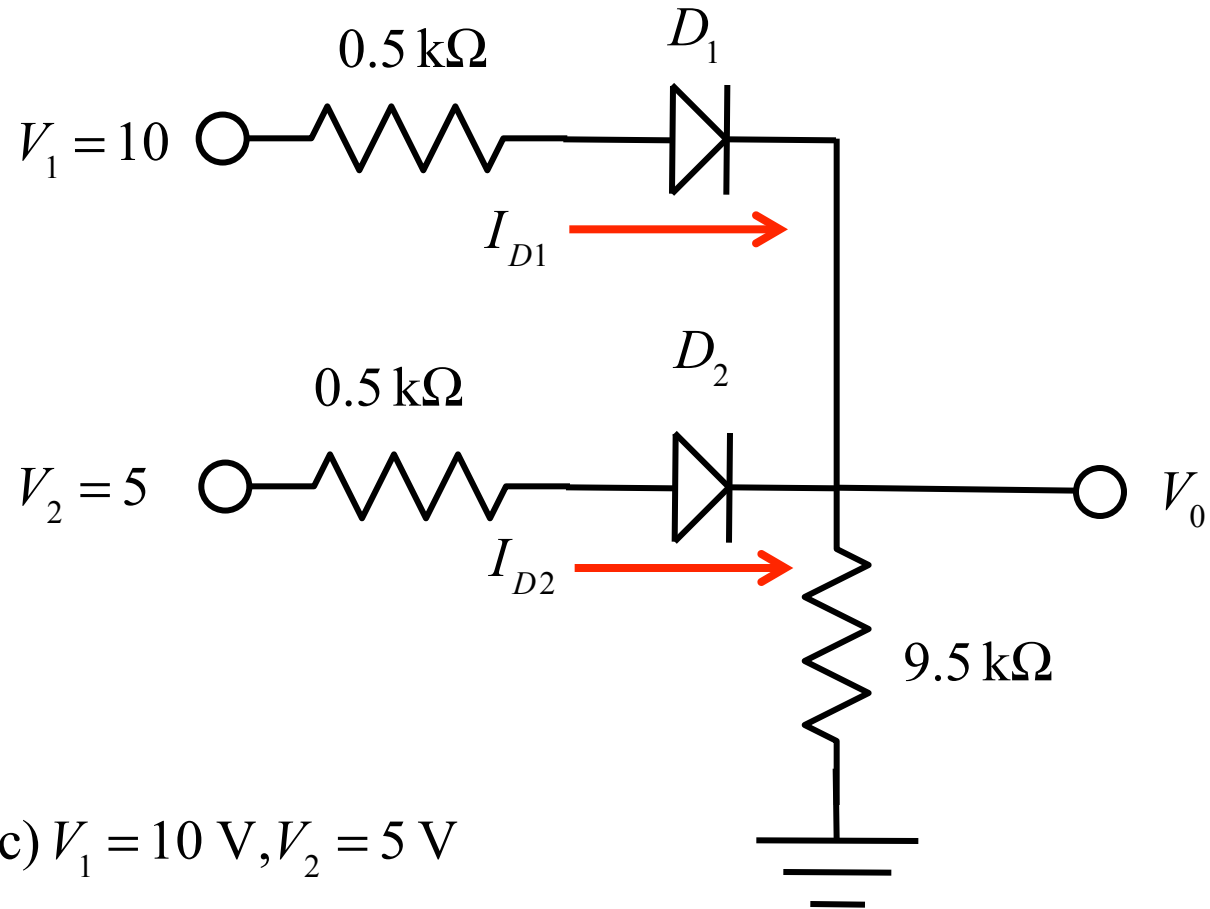
- a) $V_1 = 10 \text{ V}, V_2 = 0 \text{ V}$
- b) $V_1 = 5 \text{ V}, V_2 = 0 \text{ V}$
- c) $V_1 = 10 \text{ V}, V_2 = 5 \text{ V}$
- d) $V_1 = 10 \text{ V}, V_2 = 10 \text{ V}$

a)



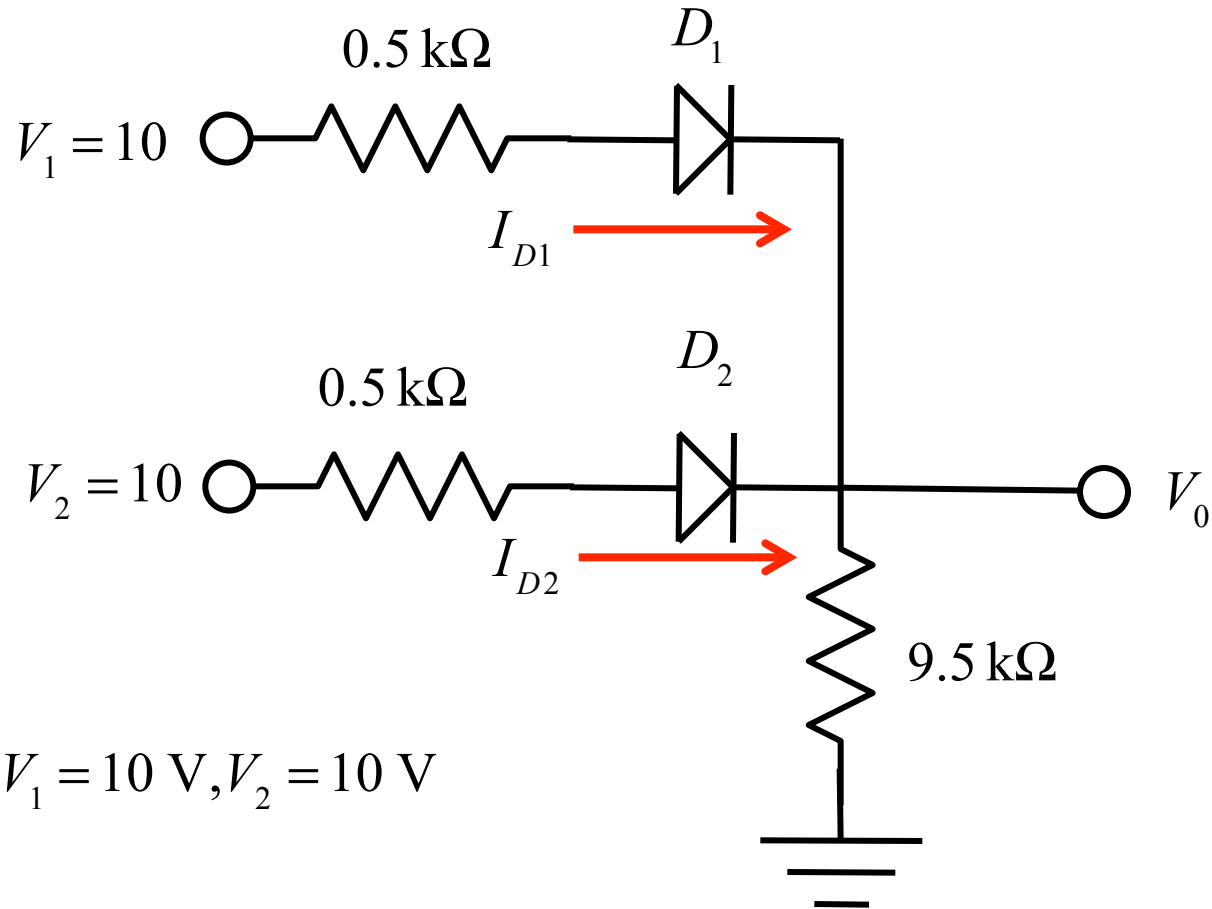
a) $V_1 = 10 \text{ V}, V_2 = 0 \text{ V}$

c)



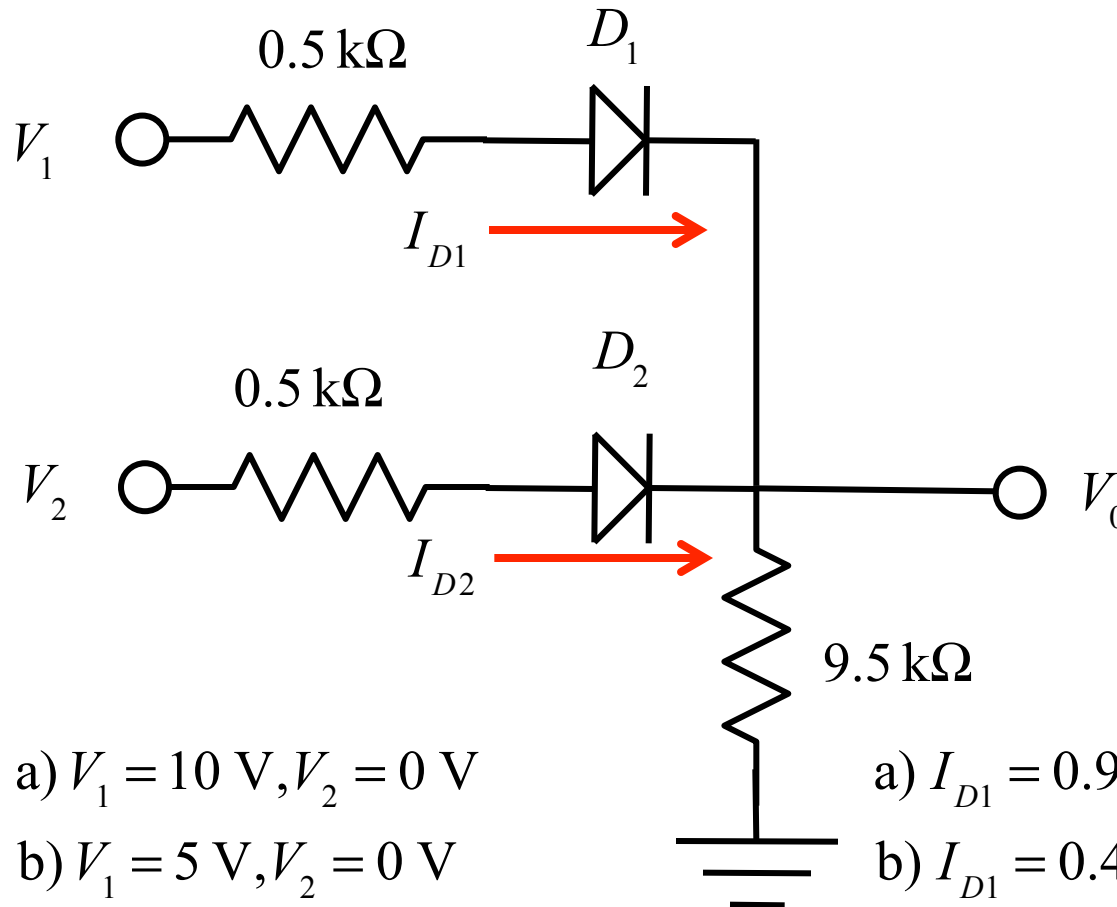
c) $V_1 = 10\text{ V}, V_2 = 5\text{ V}$

d)



d) $V_1 = 10 \text{ V}, V_2 = 10 \text{ V}$

Examples: Answers

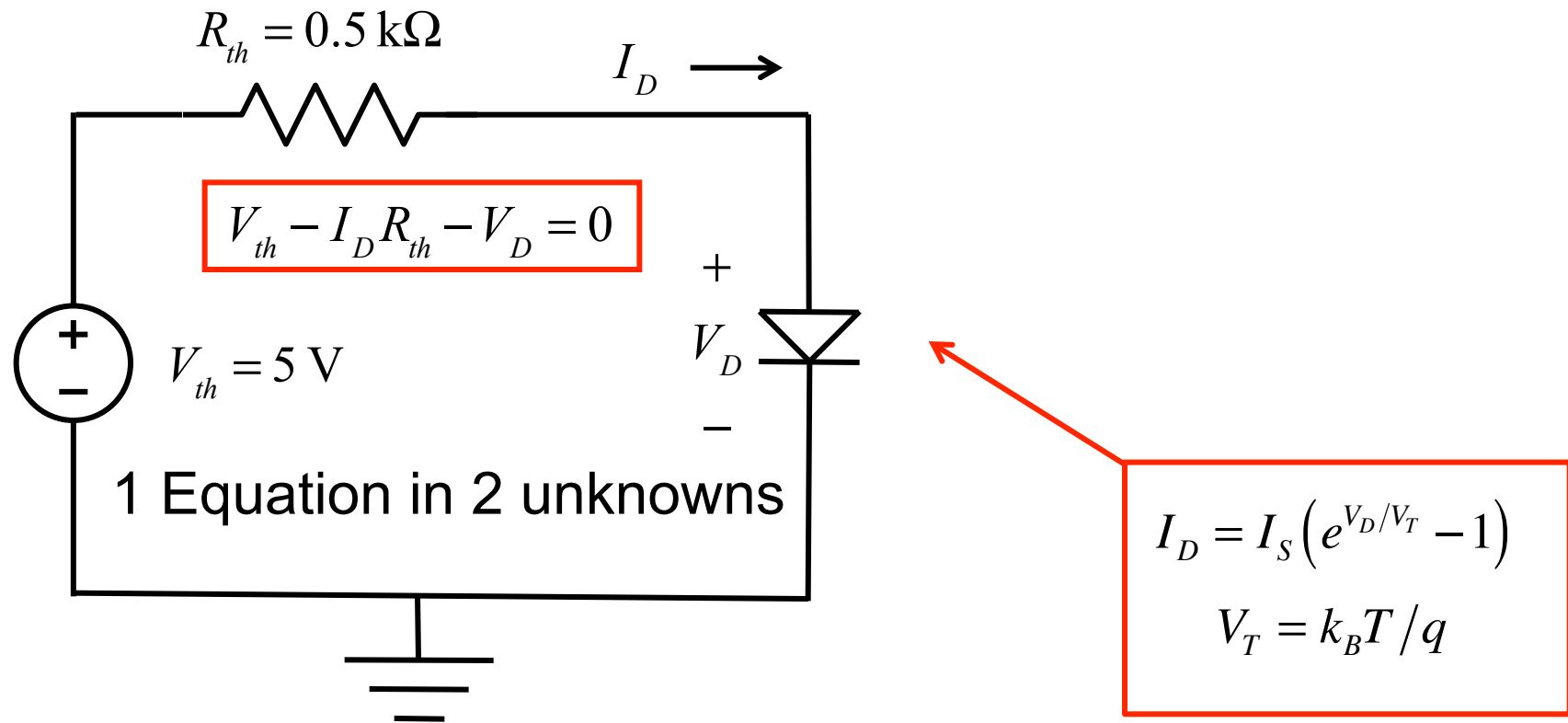


Find V_0 and the two diode currents

- a) $V_1 = 10 \text{ V}, V_2 = 0 \text{ V}$
- b) $V_1 = 5 \text{ V}, V_2 = 0 \text{ V}$
- c) $V_1 = 10 \text{ V}, V_2 = 5 \text{ V}$
- d) $V_1 = 10 \text{ V}, V_2 = 10 \text{ V}$

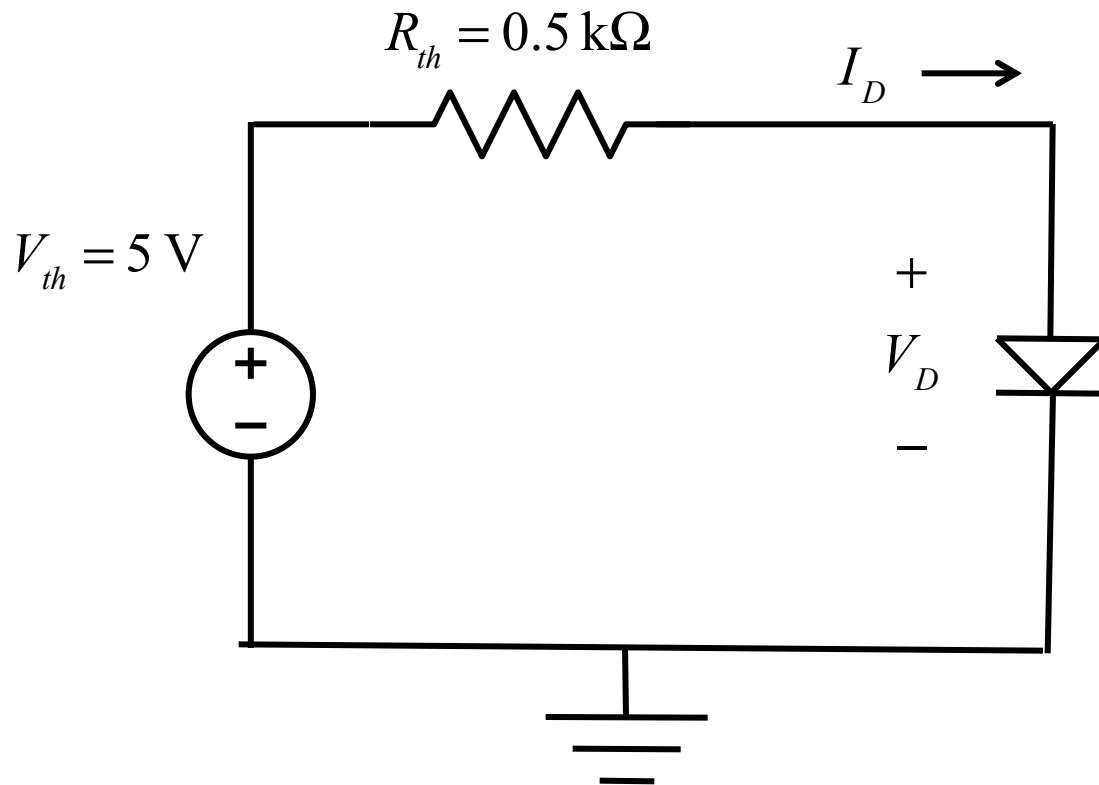
- a) $I_{D1} = 0.93 \text{ mA}, I_{D2} = 0 \text{ mA}, V_0 = 8.8 \text{ V}$
- b) $I_{D1} = 0.43 \text{ mA}, I_{D2} = 0 \text{ mA}, V_0 = 4.1 \text{ V}$
- c) $I_{D1} = 0.93 \text{ mA}, I_{D2} = 0 \text{ mA}, V_0 = 8.8 \text{ V}$
- d) $I_{D1} = 0.48 \text{ mA}, I_{D2} = 0.48 \text{ mA}, V_0 = 9.1 \text{ V}$

Analyze the circuit (exponential model)



Need another equation for $V_D(I_D)$ or $I_D(V_D)$

Analyze the circuit (exponential model)



$$V_{th} - I_D R_{th} - V_D = 0 \quad (1)$$

$$I_D = I_S (e^{V_D/V_T} - 1) \quad (2)$$

$$I_D = (V_{th} - V_D) / R_{th}$$

$$I_D = I_S e^{V_D/V_T}$$

$$I_S e^{V_D/V_T} = (V_{th} - V_D) / R_{th}$$

Graphical approach

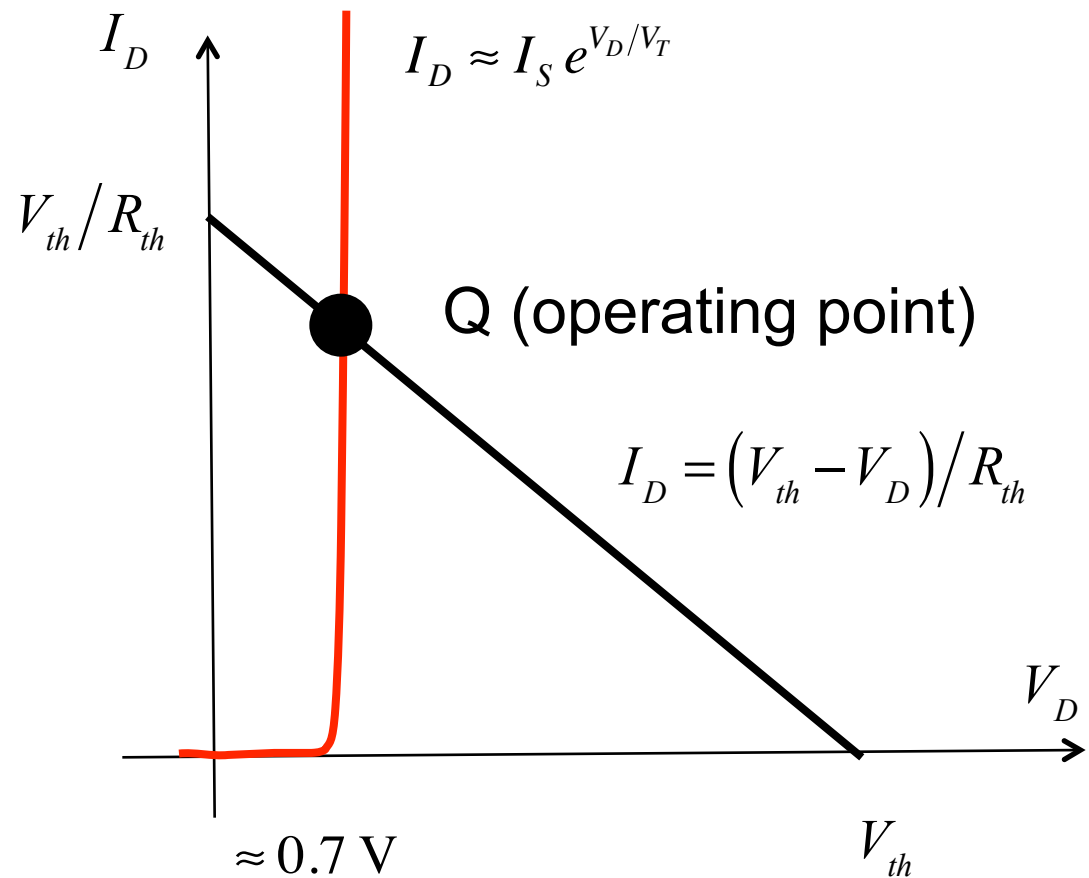
Circuit:

$$I_D = (V_{th} - V_D) / R_{th}$$

“load line”

Diode:

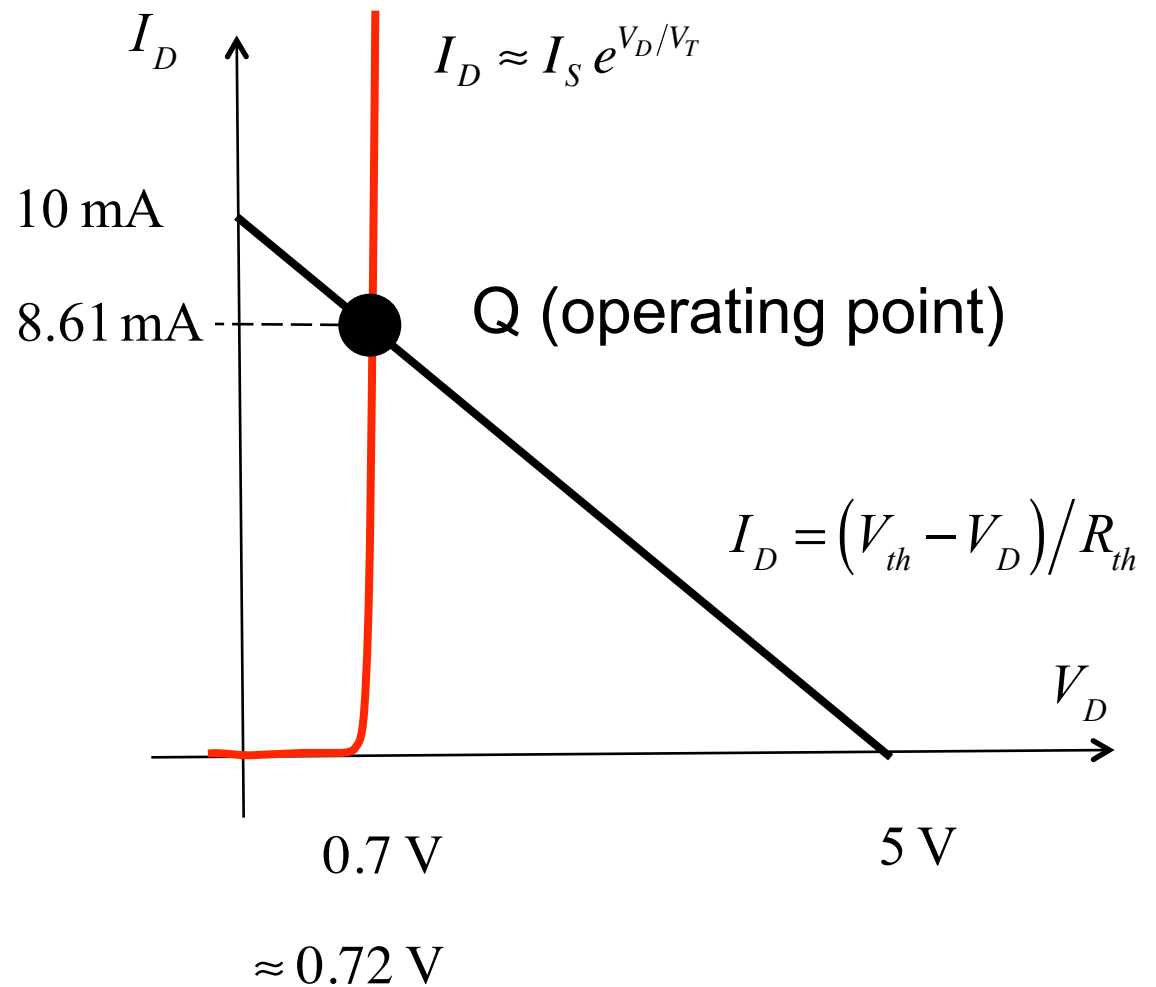
$$I_D = I_S e^{qV_D/k_B T}$$



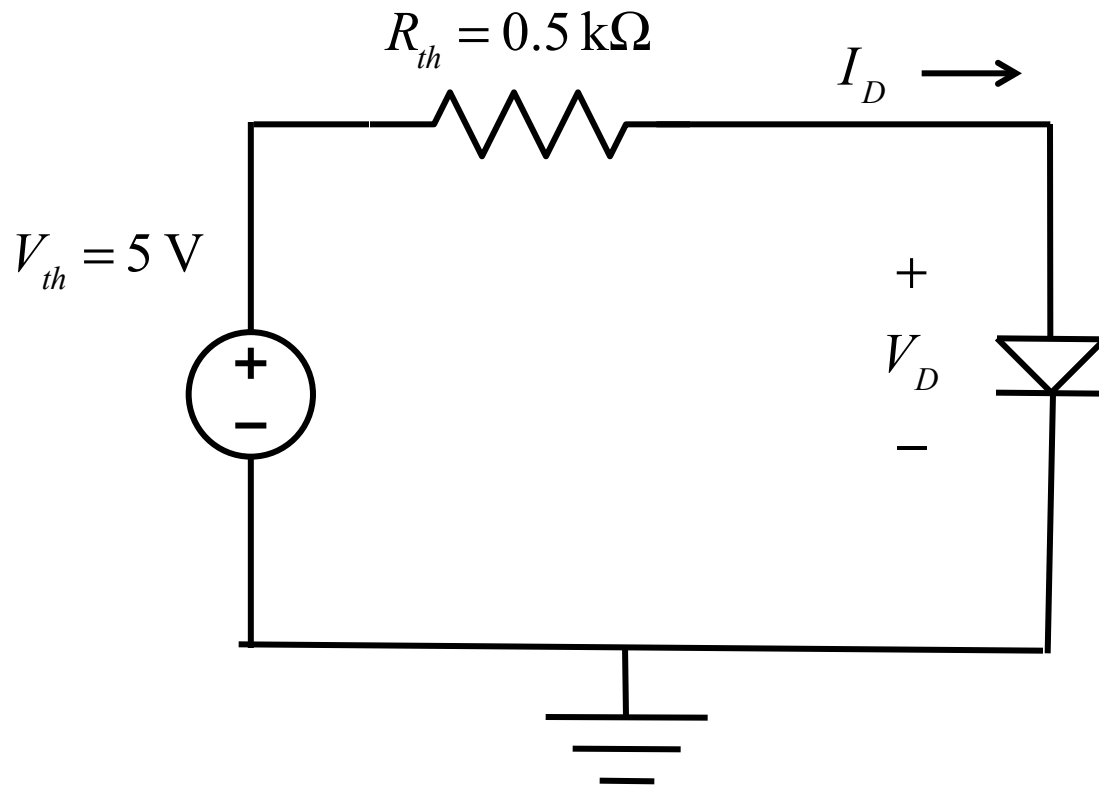
For our circuit...

$$V_{th} = 5 \text{ V}$$

$$R_{th} = 0.5 \text{ k}\Omega$$



Analyze the circuit (exponential model)



$$V_{th} - I_D R_{th} - V_D = 0 \quad (1)$$

$$I_D = I_S (e^{V_D/V_T} - 1) \quad (2)$$

$$I_D = (V_{th} - V_D) / R_{th}$$

graphical analysis

$$I_D = I_S e^{V_D/V_T}$$

numerical analysis \longrightarrow

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$$I_S e^{V_D/V_T} = (V_{th} - V_D) / R_{th}$$

Numerical solution

$$V_{th} - \left(I_S e^{V_D/V_T} \right) R_{th} - V_D = 0$$

$$5 - \left(I_S e^{V_D/0.026} \right) 500 - V_D = 0$$

$$I_S = 10^{-14} \text{ A}$$

$$5 - \left(10^{-14} e^{V_D/0.026} \right) 500 - V_D = 0$$

Guess V_D

Compute LHS

Is LHS = 0?

Try new guess and repeat

| V_D | LHS |
|---------------|---------------|
| 0.7 | +1.837 |
| 0.72 | -1.036 |
| 0.71 | 0.671 |
| 0.713 | 0.226 |
| 0.714 | 0.065 |
| 0.715 | -0.101 |
| 0.7145 | -0.017 |

$$I_D = 10^{-14} e^{0.7145/0.026} = 8.61 \text{ mA}$$

Summary

The ideal diode is a very simple, sometimes good enough model for a diode.

The constant-voltage-drop model is better, usually acceptable for first-pass, analysis by hand. The one model parameter, V_D , is generally between 0.6 – 0.8 V for Si diodes.

The exponential model is the best. It is nonlinear which makes it harder to use for hand analysis. The one model parameter, I_S , needs to be specified.

Real and ideal diodes

- 1) Ideal vs. “real” diodes
- 2) Circuit analysis using ideal (or C-V-D) diodes
- 3) Circuit analysis using real diodes

